TOSHIBA Field Effect Transistor Silicon P Channel Junction Type

2SJ108

Low Noise Audio Amplifier Applications

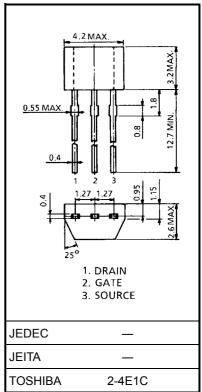
- Recommended for first stages of EQ amplifiers and MC head amplifiers.
- High $|Y_{fs}|$: $|Y_{fs}| = 22 \text{ mS (typ.)}$

 $(V_{DS} = -10 \text{ V}, V_{GS} = 0, I_{DSS} = -3 \text{ mA})$

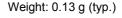
- Low noise: $En = 0.95 \text{ nV/Hz}^{1/2}$ (typ.) (VDC = -10 V JD = -1 mA f
 - $(V_{DS} = -10 V, I_D = -1 mA, f = 1 kHz)$
- High input impedance: I_{GSS} = 1.0 nA (max) (V_{GS} = 25 V)
- Complementary to 2SK370
- Small package

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V _{GDS}	25	V
Gate current	IG	-10	mA
Drain power dissipation	PD	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

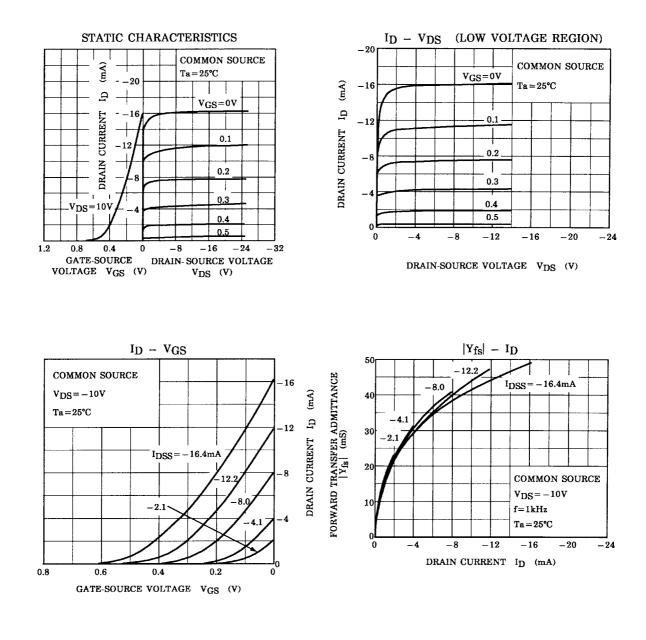


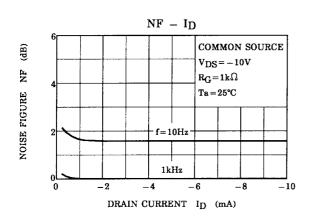
Electrical Characteristics (Ta = 25°C)

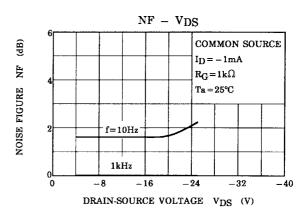


Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I _{GSS}	$V_{GS} = 25 \text{ V}, \text{ V}_{DS} = 0$	_		1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0, I_G = 100 \ \mu A$	25			V
Drain current	I _{DSS} (Note)	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0$	-2.6	_	-20	mA
Gate-source cut-off voltage	V _{GS (OFF)}	$V_{DS} = -10 \ V, \ I_D = -0.1 \ \mu A$	0.15	_	2.0	V
Forward transfer admittance	Y _{fs}	$V_{DS} = -10 V$, $V_{GS} = 0$, f = 1 kHz	8	22		mS
Input capacitance	C _{iss}	$V_{DS} = -10 V$, $V_{GS} = 0$, f = 1 MHz	_	105		pF
Reverse transfer capacitance	C _{rss}	$V_{GD} = 10 \text{ V}, \text{ I}_{D} = 0, \text{ f} = 1 \text{ MHz}$	_	32		pF
Noise figure –	NF (1)	V_{DS} = -10 V, I _D = -1 mA, R _G = 1 k Ω , f = 10 Hz	—	1.0	10	dB
	NF (2)	V_{DS} = -10 V, I _D = -1 mA, R _G = 1 k Ω , f = 1 kHz	_	0.5	2	

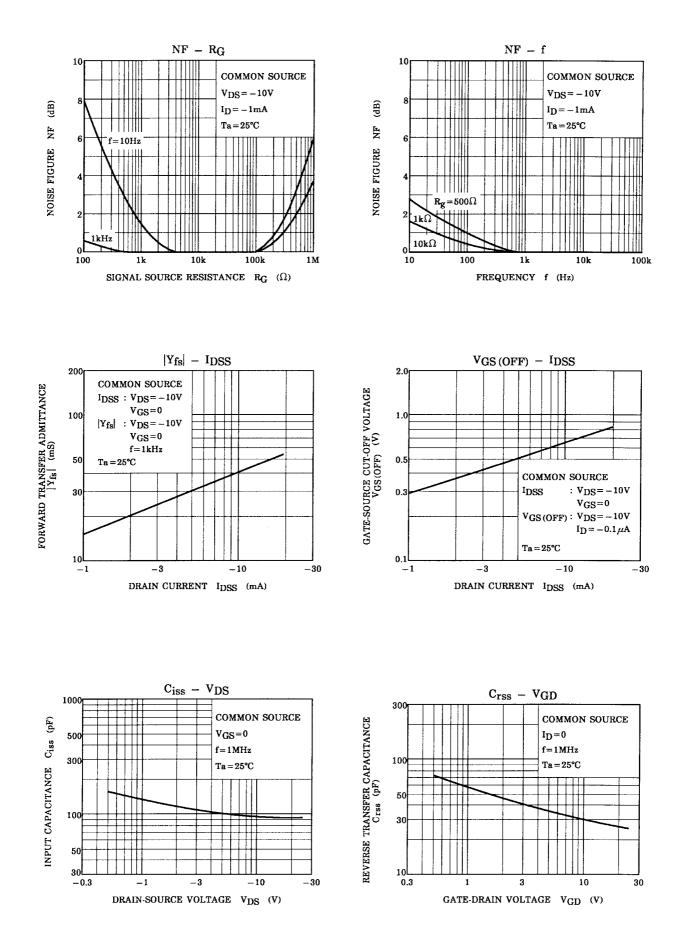
Note: I_{DSS} classification GR: -2.6~-6.5 mA, BL: -6.0~-12 mA, V: -10~-20 mA



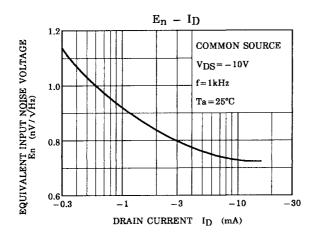


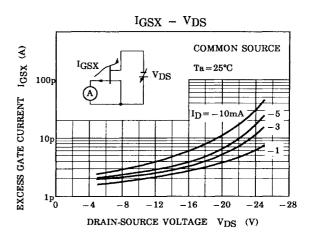


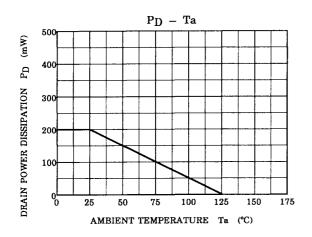
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